

# Physics and chemistry of nanostructures

Progress Navolchi project

March 12th, 2012

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Ghent University  
Belgium

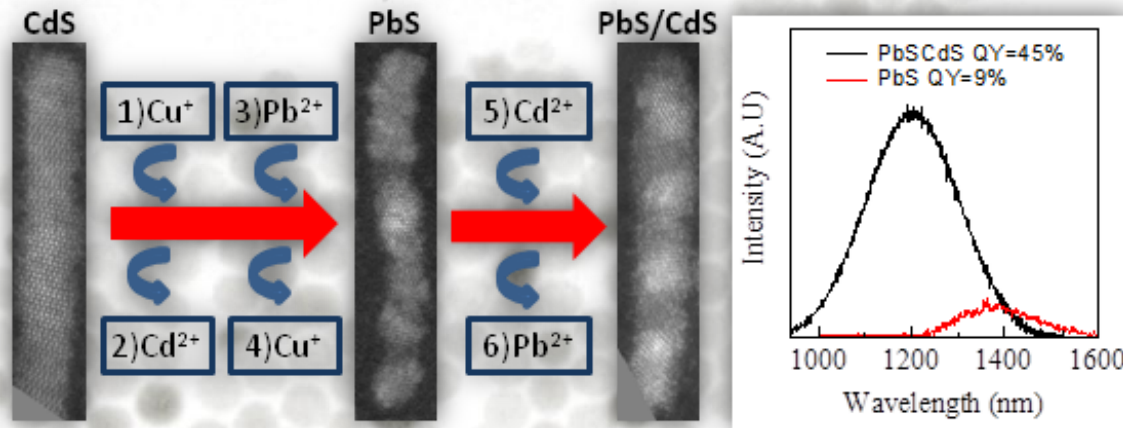


# Outline

- **Materials**
  - PbX/CdX heterostructures
- **Processing**
- **Properties**
  - Absorption enhancement in QD monolayers
  - Intraband absorption with PbX QDs
  - Pump-probe measurements -> amplification
- **Devices**
  - Absorbance of functionalized waveguides
- **Planning of future work**



# PbS/CdS multiple dot-in-rods

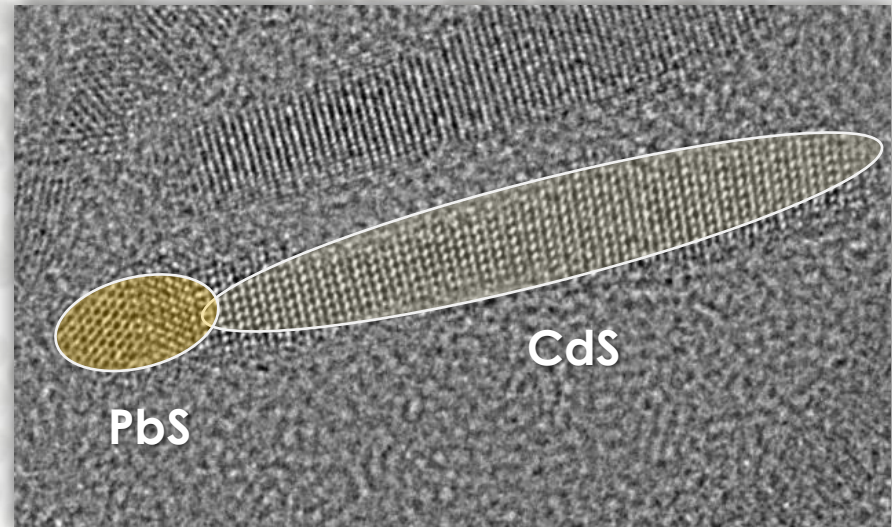
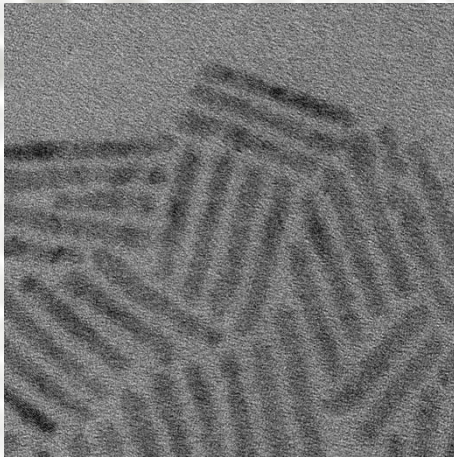
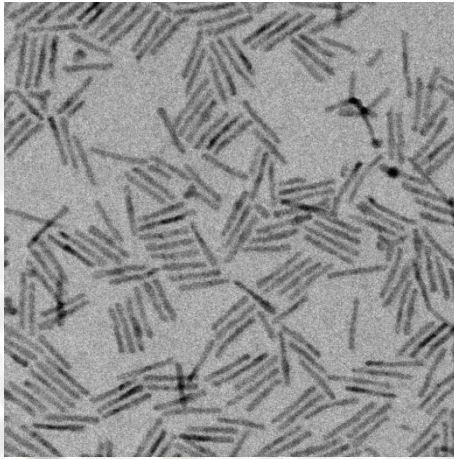


- Successive cation exchange steps transform original CdS rod into a PbS/CdS multiple dot-in-rod
- Passivation by CdS enhances PLQY to 45-55%

Justo *et al.*, *J. Am. Chem. Soc.* 2012, 134, 5484–5487

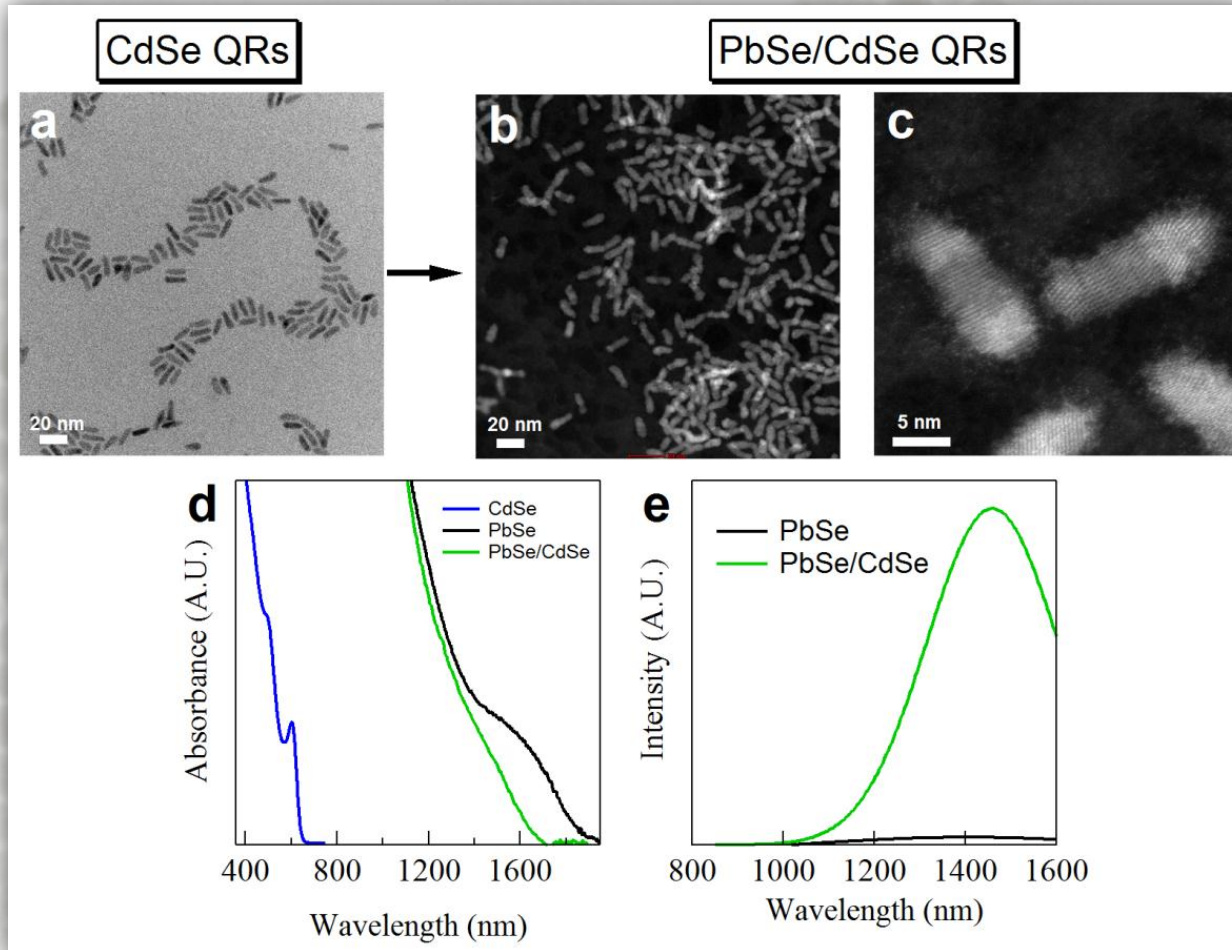
# PbS/CdS dot-in-rods

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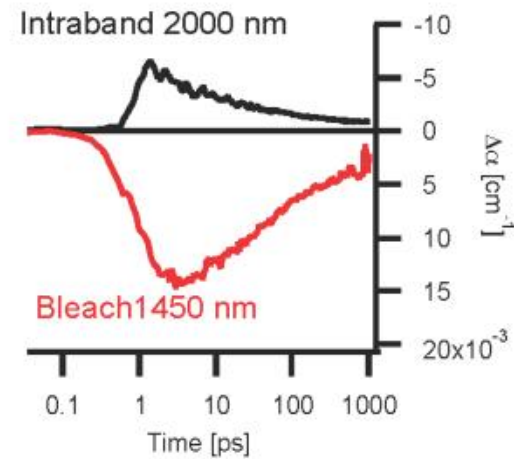
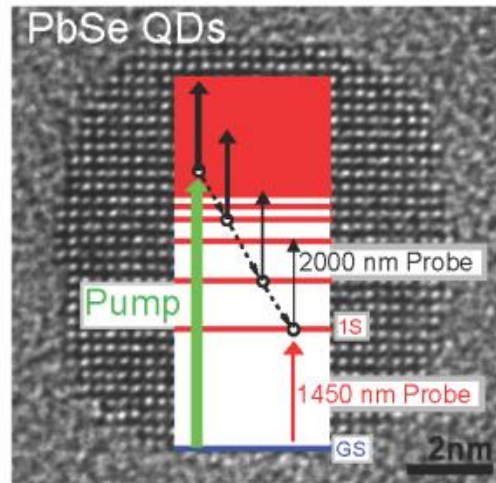


# PbSe/CdSe rods

Similar synthesis as PbS/CdS dot-in-rods



# Intraband absorption



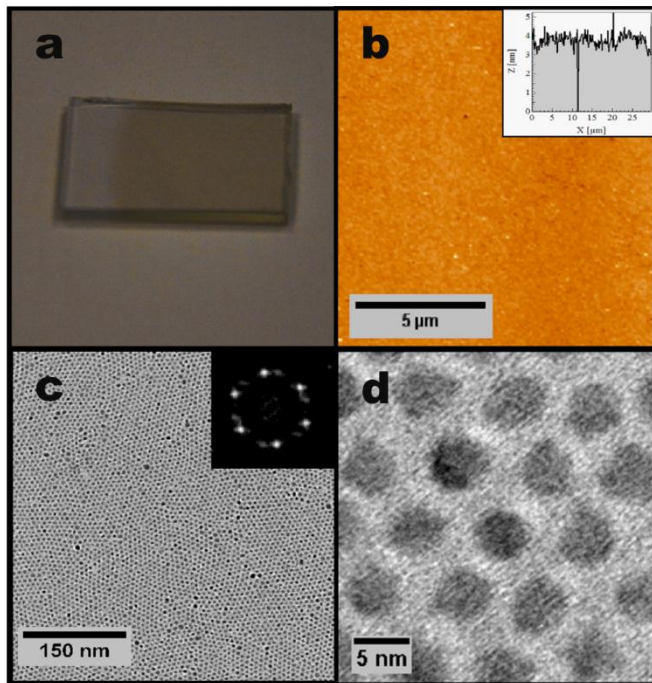
- Potential for switching
- Setback for gain (raises threshold)

De Geyter et al., accepted by *ACS Nano*

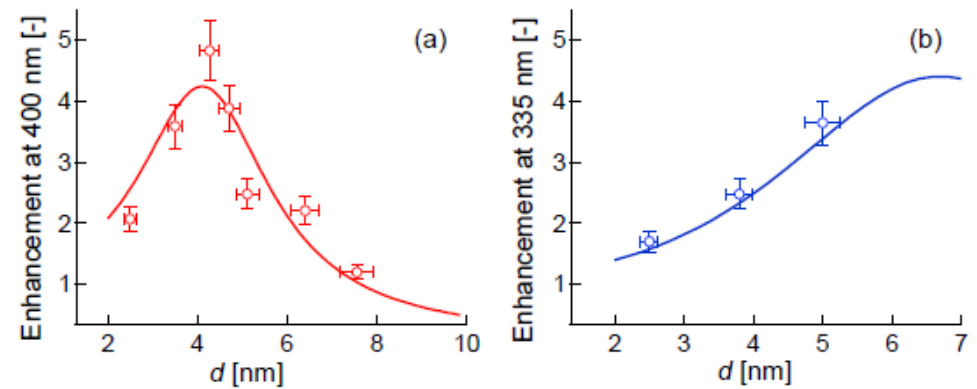


# Absorption enhancement

Measurement of absorption cross section of QDs in close packed monolayer



$$E = \frac{\sigma_{film}}{\sigma_{sol}}$$

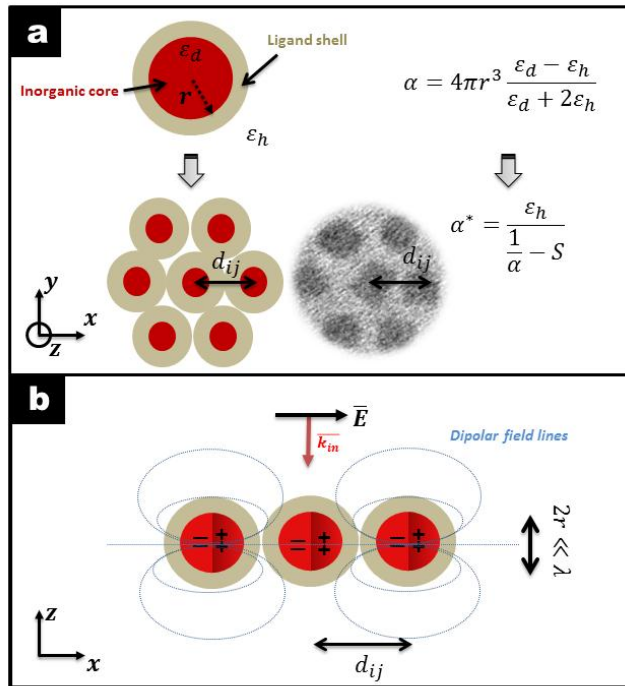


Geiregat et al., under review at *ACS Nano*

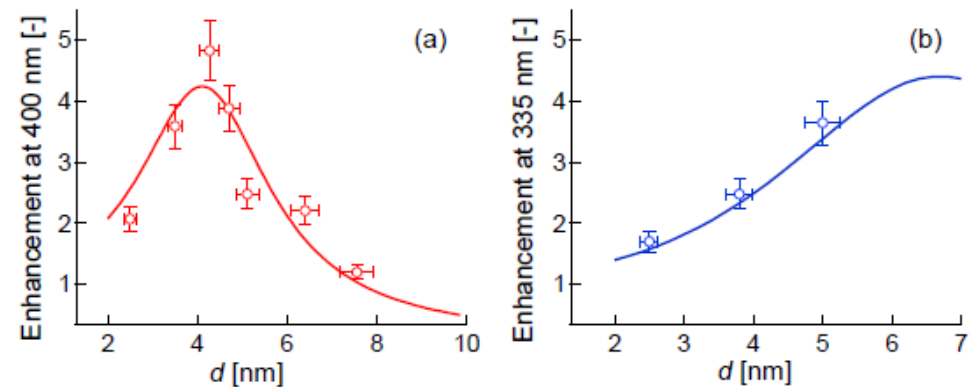


# Absorption enhancement

## Measurement of absorption cross section of QDs in close packed monolayer

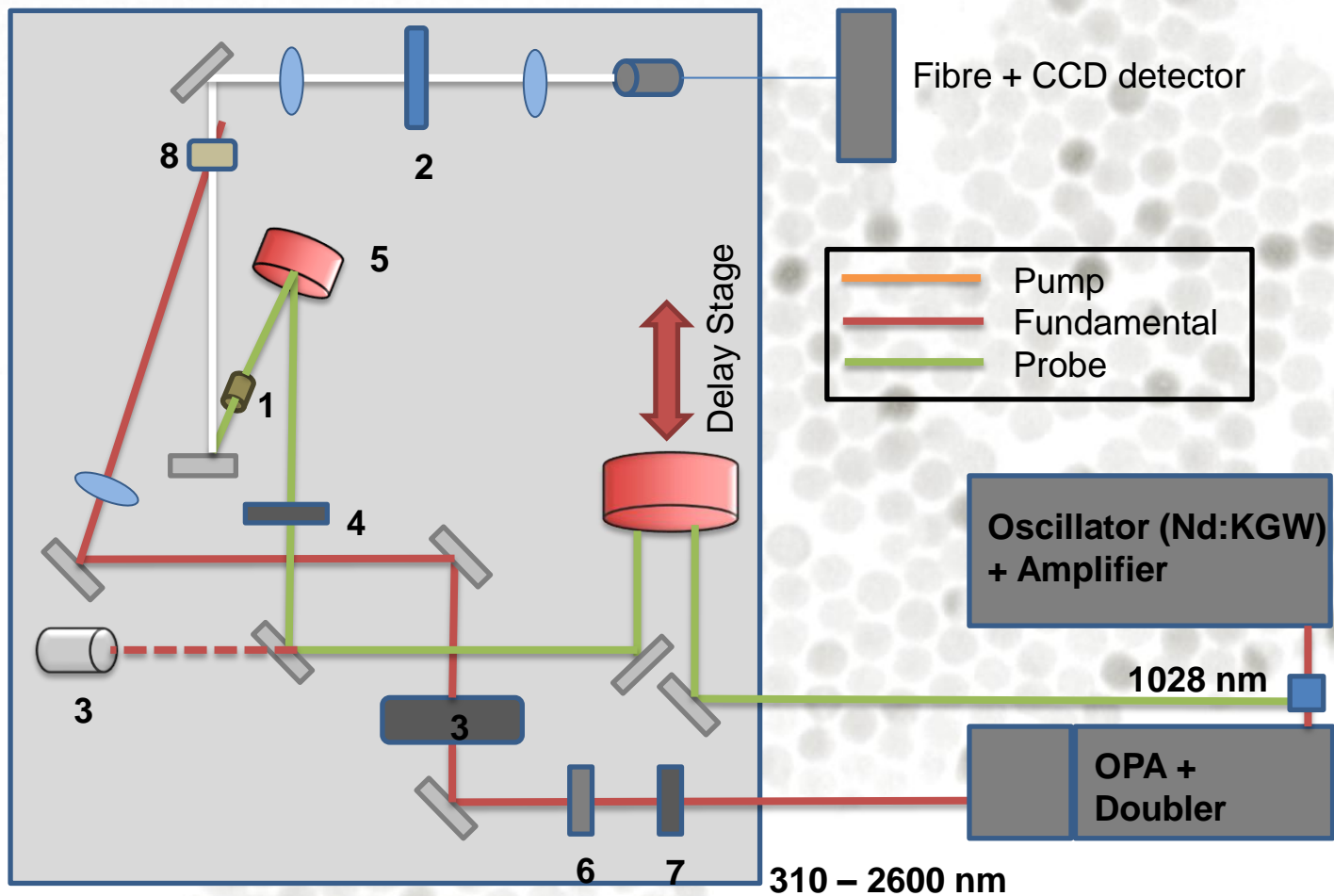


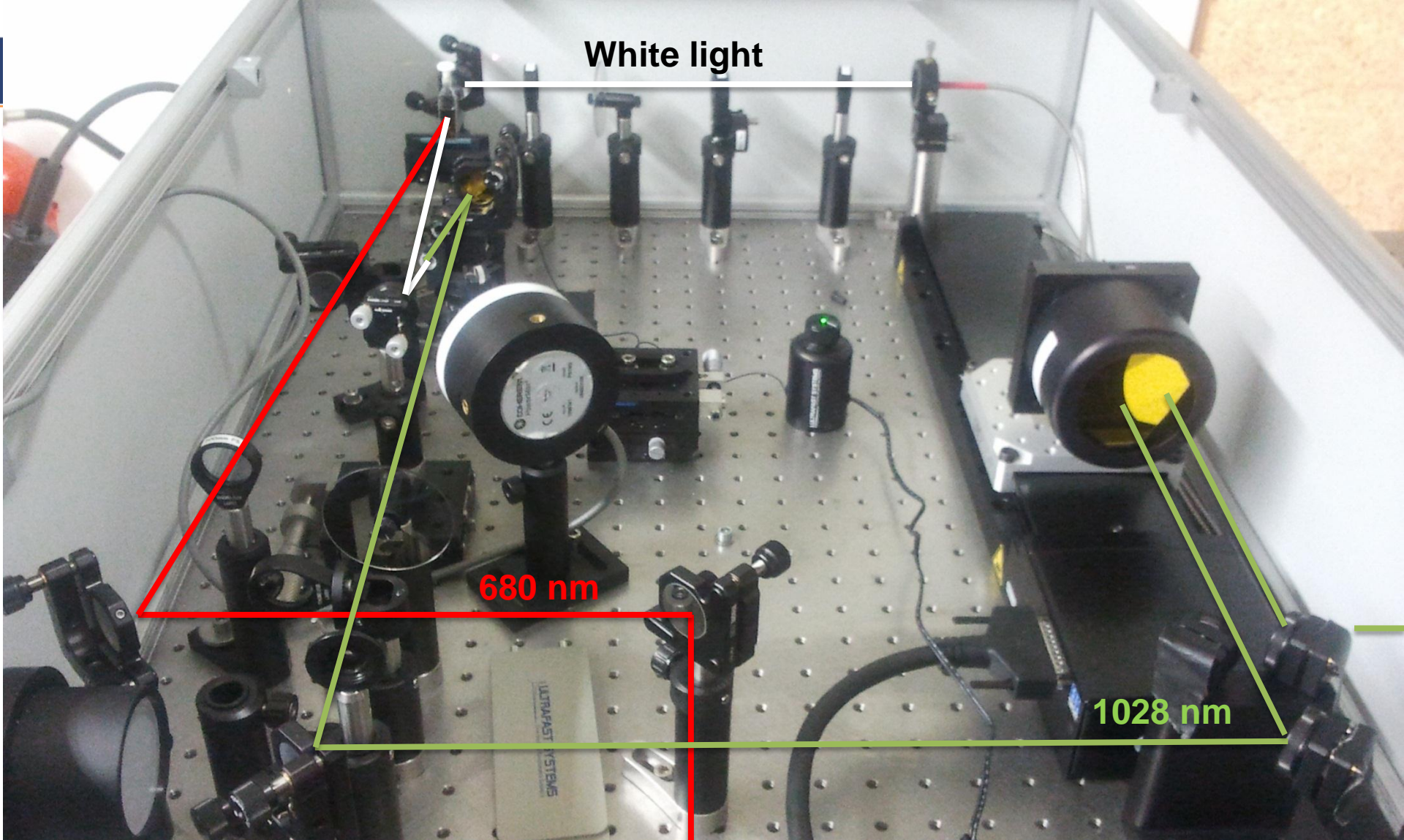
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White light

680 nm

1028 nm

White light (up to 1600 nm) is created in sapphire crystal through 1028 nm pumping (fundamental of laser oscillator Nd:KGW).



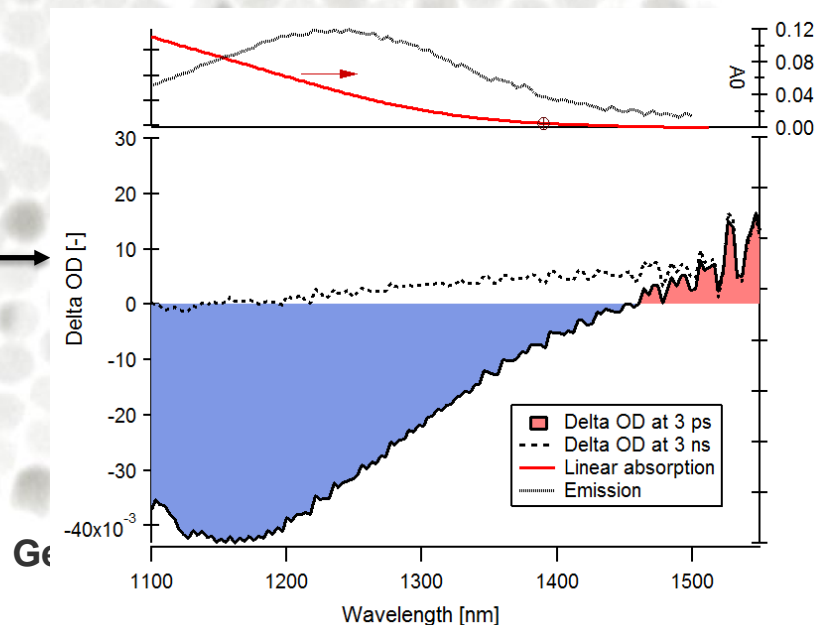
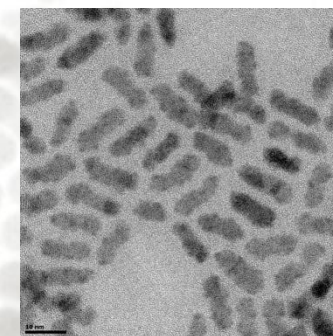
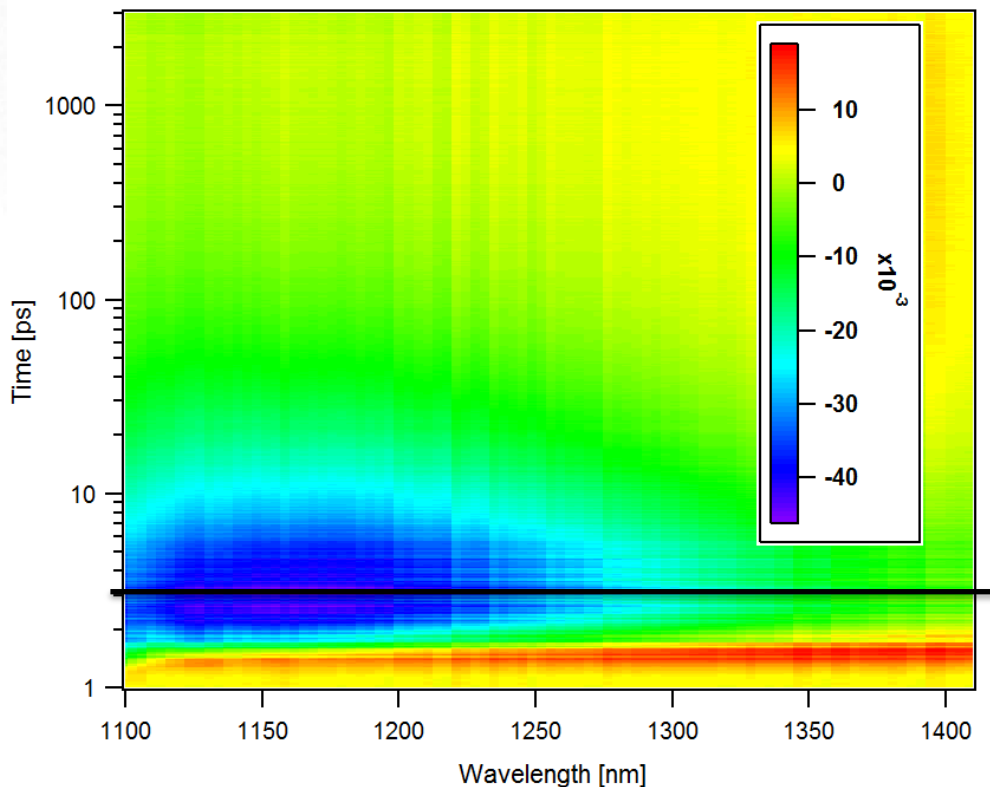
Physics and Chemistry of Nanostructures Group

Represented by



# PbS rods 4 x 12.8 nm

## Analysis around Band Gap

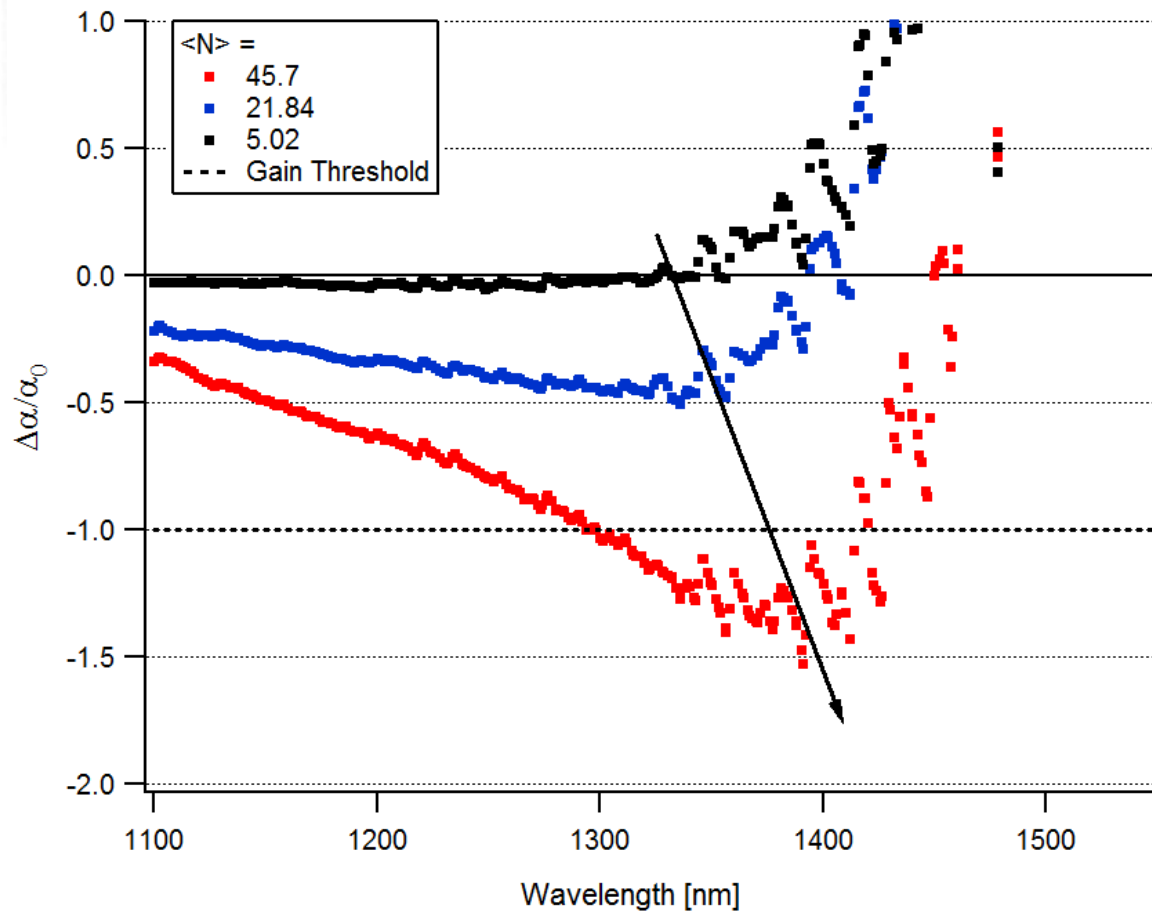


White light TA spectrum  
(now reliable up to 1600):

- Bleach band
- PA band



# Pump dependent spectra



Bleach maximum redshifts due to increased multi-exciton shifts

At gain transition (ca. 1400 nm) you evolve from an absorbing transition at low fluence to a full bleach at high fluence.

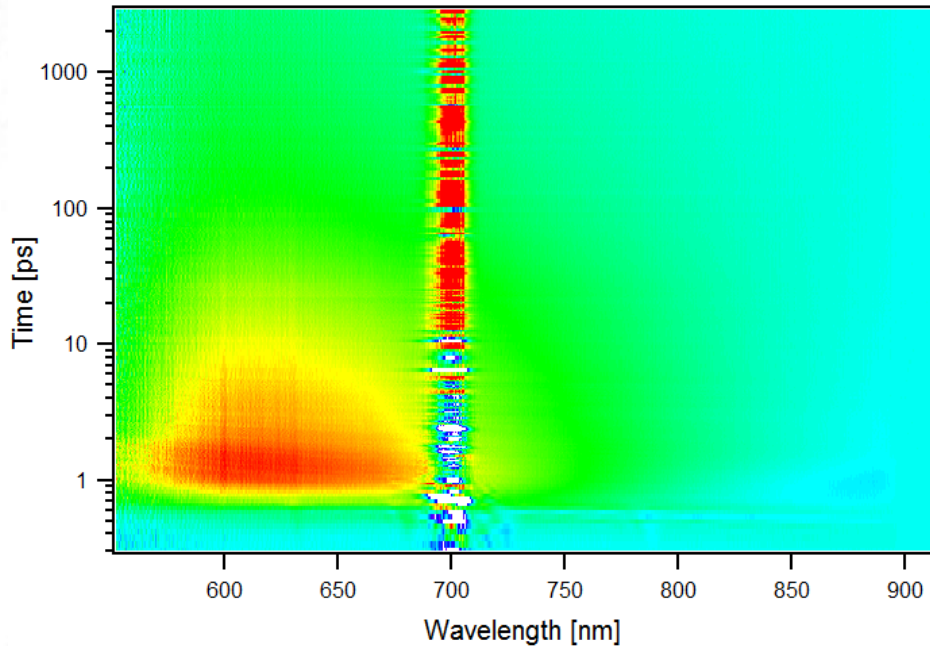
## How ?

Competition between PA and gain buildup with different dependence on carrier density?



# PbS rods 4 x 12.8 nm

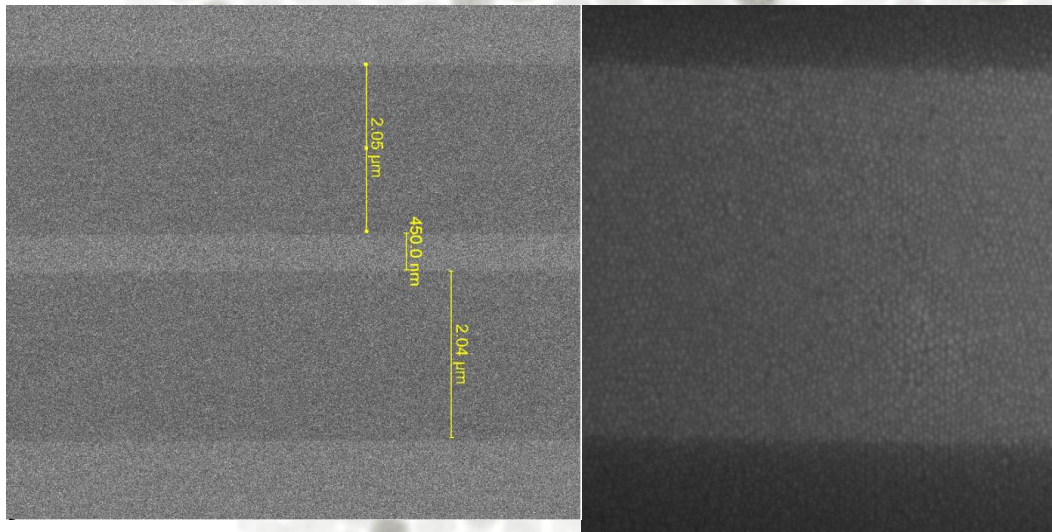
## Analysis in the visible



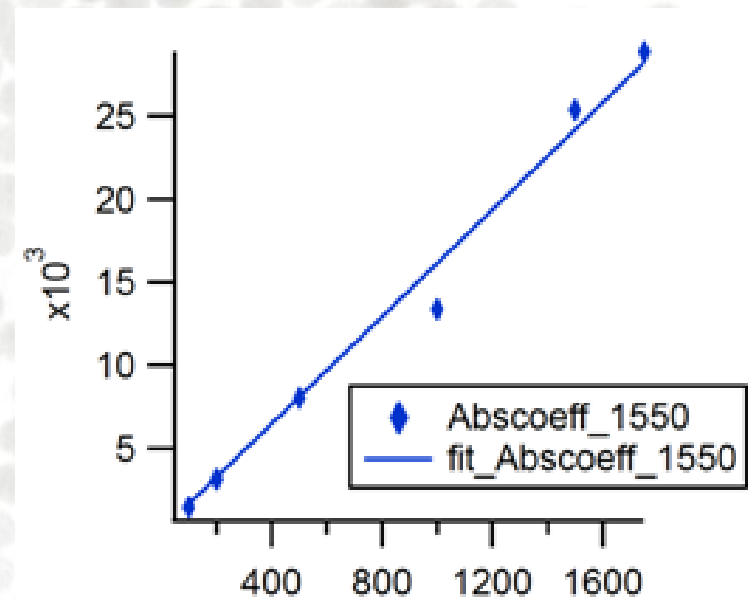
- Pronounced PA absorbance also for supra bandgap light
- Measurements also done on PbS dots – analysis ongoing

# QD functionalized waveguide

Absorbance of QD functionalized waveguide



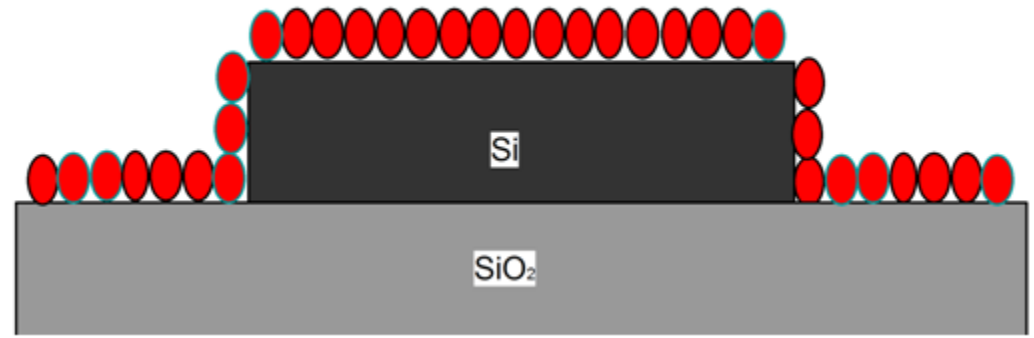
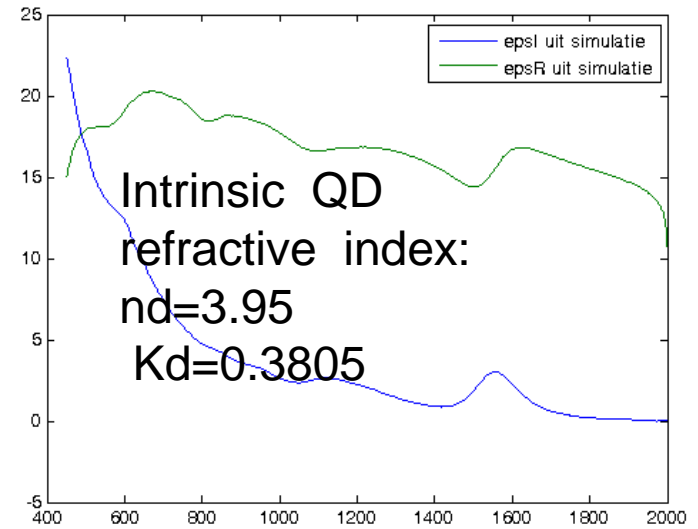
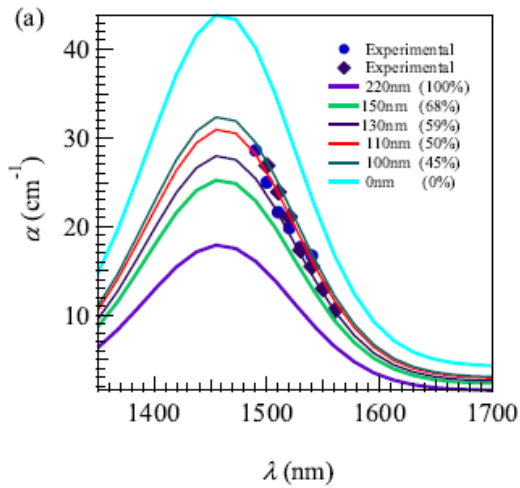
$$loss, wg, L = \alpha \Delta L = \frac{\Delta P, dB}{10 \log(e)}$$



$\Delta L$  *um*

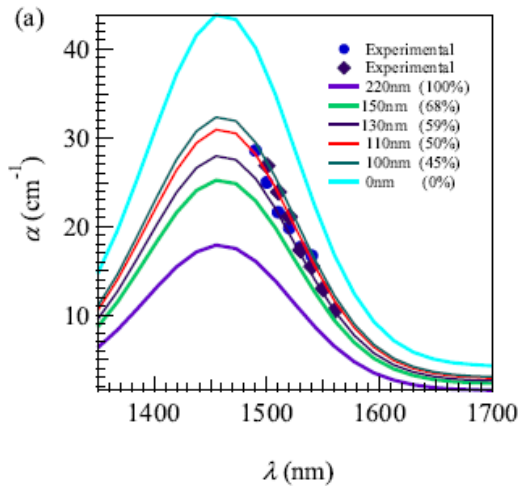
# QD functionalized waveguides

Non-planarized



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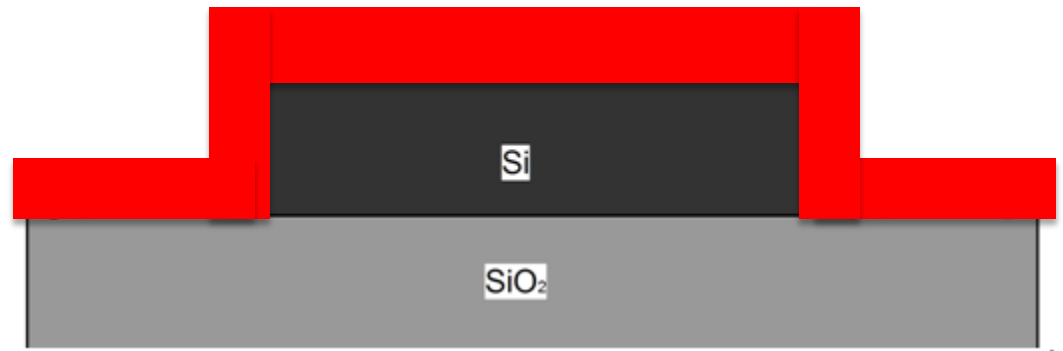
Non-planarized



Effective medium refractive index (MG):

$$n=1.876$$

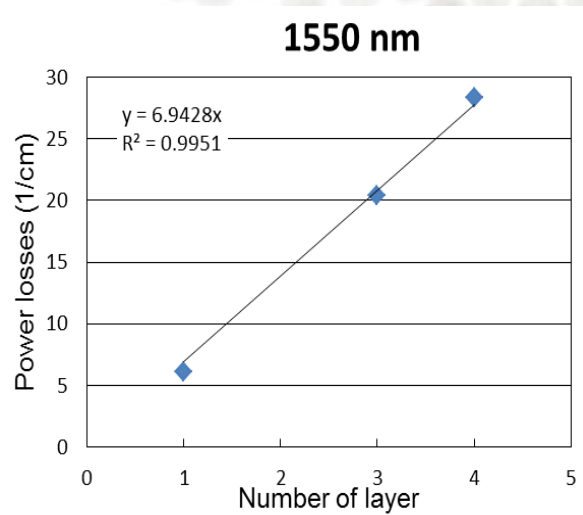
$$K=0.034$$





# QD functionalized waveguides

Planarized as functions of layer thickness



# Future work

- **Materials synthesis**
  - HR-TEM analysis of PbSe/CdSe QDs
- **Continuation of Transient Absorption spectroscopy**
  - Benchmarking relative to PbS and PbS/CdS QDs
  - Analysis of PbS/CdS and PbSe/CdSe dot(s)-in-rod
- **Sample exchange with Valencia**
  - New batches have been sent

